N-Channel 20-V(D-S) MOSFET

## FEATURE

TrenchFET Power MOSFET

## APPLICATIONS

- Load Switch for Portable Devices
- DC/DC Converter



## MARKING: A2SHB

## Maximum ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ unless otherwise noted)



| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Drain-Source Voltage | $\mathrm{V}_{\mathrm{DS}}$ | 20 | V |
| Gate-Source Voltage | $\mathrm{V}_{\mathrm{GS}}$ | $\pm 8$ |  |
| Continuous Drain Current | $\mathrm{ID}_{\mathrm{D}}$ | 2.8 | A |
| Continuous Source-Drain Current(Diode Conduction) | $\mathrm{IS}_{\mathrm{S}}$ | 0.6 |  |
| Power Dissipation | $\mathrm{PD}_{\mathrm{D}}$ | 357 | W |
| Thermal Resistance from Junction to Ambient $(\mathrm{t} \leq 5 \mathrm{~s})$ | $\mathrm{R}_{\text {өJA }}$ | 150 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Operating Junction | $\mathrm{T}_{\mathrm{J}}$ | $-55 \sim+150$ | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | $\mathrm{T}_{\text {STG }}$ |  |  |

Electrical characteristics ( $\mathrm{T}_{\mathrm{a}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ unless otherwise noted)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Static |  |  |  |  |  |  |
| Drain-source breakdown voltage | $\mathrm{V}_{\text {(BR)DSS }}$ | $V_{G S}=0 \mathrm{~V}, \mathrm{ID}=10 \mu \mathrm{~A}$ | 20 |  |  | V |
| Gate-threshold voltage | VGs(th) | $\mathrm{V}_{\mathrm{DS}}=\mathrm{V}_{\mathrm{GS}}, \mathrm{ld}=50 \mu \mathrm{~A}$ | 0.65 | 0.95 | 1.2 |  |
| Gate-body leakage | Igss | $V_{\text {ds }}=0 \mathrm{~V}, \mathrm{~V}_{\text {gs }}= \pm 8 \mathrm{~V}$ |  |  | $\pm 100$ | nA |
| Zero gate voltage drain current | IDSS | $V_{\text {ds }}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{gs}}=0 \mathrm{~V}$ |  |  | 1 | $\mu \mathrm{A}$ |
| Drain-source on-resistance ${ }^{\text {a }}$ | rDS(on) | $\mathrm{VGs}=4.5 \mathrm{~V}, \mathrm{ld}=3.6 \mathrm{~A}$ |  | 0.045 | 0.060 | $\Omega$ |
|  |  | $\mathrm{VGs}=2.5 \mathrm{~V}, \mathrm{ld}=3.1 \mathrm{~A}$ |  | 0.070 | 0.115 |  |
| Forward transconductance ${ }^{\text {a }}$ | gis | $V_{\text {ds }}=5 \mathrm{~V}, \mathrm{ld}=3.6 \mathrm{~A}$ |  | 8 |  | S |
| Diode forward voltage | $V_{S D}$ | $\mathrm{Is}_{\mathrm{s}}=0.94 \mathrm{~A}, \mathrm{~V}_{\mathrm{Gs}}=0 \mathrm{~V}$ |  | 0.76 | 1.2 | V |
| Dynamic |  |  |  |  |  |  |
| Total gate charge | $Q_{g}$ | V Ds $=10 \mathrm{~V}, \mathrm{VGs}=4.5 \mathrm{~V}, \mathrm{ld}=3.6 \mathrm{~A}$ |  | 4.0 | 10 | nC |
| Gate-source charge | $\mathrm{Q}_{\mathrm{gs}}$ |  |  | 0.65 |  |  |
| Gate-drain charge | $\mathrm{Q}_{\mathrm{gd}}$ |  |  | 1.5 |  |  |
| Input capacitance ${ }^{\text {b }}$ | $\mathrm{C}_{\text {iss }}$ | Vds $=10 \mathrm{~V}, \mathrm{VGS}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 300 |  | pF |
| Output capacitance ${ }^{\text {b }}$ | Coss |  |  | 120 |  |  |
| Reverse transfer capacitance ${ }^{\text {b }}$ | $\mathrm{C}_{\text {rss }}$ |  |  | 80 |  |  |
| Switching ${ }^{\text {b }}$ |  |  |  |  |  |  |
| Turn-on delay time | $\mathrm{td}_{\text {(on) }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=5.5 \Omega, \mathrm{ID} \approx 3.6 \mathrm{~A}, \\ & \mathrm{~V}_{\mathrm{GEN}}=4.5 \mathrm{~V}, \mathrm{Rg}=6 \Omega \end{aligned}$ |  | 7 | 15 | ns |
| Rise time | tr |  |  | 55 | 80 |  |
| Turn-off delay time | $\mathrm{td}_{\text {(off) }}$ |  |  | 16 | 60 |  |
| Fall time | tf |  |  | 10 | 25 |  |

## Notes :

a. Pulse Test : Pulse width $\leq 300 \mu \mathrm{~s}$, duty cycle $\leq 2 \%$.
b. These parameters have no way to verify.

## Typical Characteristics






## SOT-23-3L Package Outline Dimensions



## Plastic-Encapsulate MOSFETS

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